

## J110, J110A

## N-Channel Silicon Junction Field-Effect Transistor

- Choppers
- Commutators
- Analog Switches

Absolute maximum ratings at  $T_A = 25^\circ\text{C}$ 

|  |            |
|--|------------|
| Reverse Gate Source & Reverse Gate Drain Voltage | - 25 V     |
| Continuous Forward Gate Current                  | 50 mA      |
| Continuous Device Power Dissipation              | 360 mW     |
| Power Derating                                   | 3.27 mW/°C |

At 25°C free air temperature:

## Static Electrical Characteristics

|                                   |               | J110  |     | J110A |     | Process NJ450 |   |
|-----------------------------------|---------------|-------|-----|-------|-----|---------------|---|
|                                   |               | Min   | Max | Min   | Max | Unit          | Test Conditions                                     |
| Gate Source Breakdown Voltage     | $V_{(BR)GSS}$ | - 25  |     | - 25  |     | V             | $I_G = - 1 \mu\text{A}, V_{DS} = \emptyset\text{V}$ |
| Gate Reverse Current              | $I_{GSS}$     |       | - 3 |       | - 3 | nA            | $V_{GS} = - 15\text{V}, V_{DS} = \emptyset\text{V}$ |
| Gate Source Cutoff Voltage        | $V_{GS(OFF)}$ | - 0.5 | - 4 | - 0.5 | - 4 | V             | $V_{DS} = 5\text{V}, I_D = 1 \mu\text{A}$           |
| Drain Saturation Current (Pulsed) | $I_{DSS}$     | 10    |     | 10    |     | mA            | $V_{DS} = 15\text{V}, V_{GS} = \emptyset\text{V}$   |
| Drain Cutoff Current              | $I_{D(OFF)}$  |       | 3   |       | 3   | nA            | $V_{DS} = 5\text{V}, V_{GS} = - 10\text{V}$         |

## Dynamic Electrical Characteristics

|                                      |                   |  |    |  |    |          |   |                     |
|--------------------------------------|-------------------|--|----|--|----|----------|---|---------------------|
| Drain Source ON Resistance           | $r_{ds(on)}$      |  | 18 |  | 25 | $\Omega$ | $V_{GS} = \emptyset, V_{DS} < = 0.1\text{V}$        | $f = 1 \text{ kHz}$ |
| Drain Gate Capacitance               | $C_{gd}$          |  | 15 |  | 15 | pF       | $V_{DS} = \emptyset\text{V}, V_{GS} = - 10\text{V}$ | $f = 1 \text{ MHz}$ |
| Source Gate Capacitance              | $C_{gs}$          |  | 15 |  | 15 | pF       | $V_{DS} = \emptyset\text{V}, V_{GS} = - 10\text{V}$ | $f = 1 \text{ MHz}$ |
| Drain Gate + Source Gate Capacitance | $C_{gd} + C_{gs}$ |  | 85 |  | 85 | pF       | $V_{DS} = V_{GS} = \emptyset\text{V}$               | $f = 1 \text{ MHz}$ |

## Switching Characteristics

|                     |              | Typ |     |    |               |       |     |          |
|---------------------|--------------|-----|-----|----|---------------|-------|-----|----------|
|                     |              | Typ | Typ |    | J110          | J110A |     |          |
| Turn ON Delay Time  | $t_{d(on)}$  | 4   | 4   | ns | $V_{DD}$      | 1.5   | 1.5 | V        |
| Rise Time           | $t_r$        | 1   | 1   | ns | $V_{GS(OFF)}$ | - 5   | - 5 | V        |
| Turn OFF Delay Time | $t_{d(off)}$ | 6   | 6   | ns | $R_L$         | 150   | 150 | $\Omega$ |
| Fall Time           | $t_f$        | 30  | 30  | ns |               |       |     |          |

## TO-226AA Package

Dimensions in Inches (mm)

## Pin Configuration

1 Drain, 2 Source, 3 Gate

## Surface Mount

SMPJ110, SMPJ110A



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